

JAN 19 2005

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<b>TRANSMITTAL FORM</b>  (to be used for all correspondence after initial filing)	Application Number	10/820,447	
	Filing Date	April 7, 2004	
	First Named Inventor	Chung J. Lee	
	Art Unit	3746	
	Examiner Name		
Total Number of Pages in This Submission	8	Attorney Docket Number	DSI313CON

ENCLOSURES (Check all that apply)		
<input type="checkbox"/> Fee Transmittal Form <input type="checkbox"/> Fee Attached <input type="checkbox"/> Amendment/Reply <input type="checkbox"/> After Final <input type="checkbox"/> Affidavits/declaration(s) <input type="checkbox"/> Extension of Time Request <input type="checkbox"/> Express Abandonment Request <input checked="" type="checkbox"/> Information Disclosure Statement  <input type="checkbox"/> Certified Copy of Priority Document(s) <input type="checkbox"/> Reply to Missing Parts/Incomplete Application <input type="checkbox"/> Reply to Missing Parts under 37 CFR 1.52 or 1.53	<input type="checkbox"/> Drawing(s) <input type="checkbox"/> Licensing-related Papers <input type="checkbox"/> Petition <input type="checkbox"/> Petition to Convert to a Provisional Application <input type="checkbox"/> Power of Attorney, Revocation <input type="checkbox"/> Change of Correspondence Address <input type="checkbox"/> Terminal Disclaimer <input type="checkbox"/> Request for Refund <input type="checkbox"/> CD, Number of CD(s) _____ <input type="checkbox"/> Landscape Table on CD	<input type="checkbox"/> After Allowance Communication to TC <input type="checkbox"/> Appeal Communication to Board of Appeals and Interferences <input type="checkbox"/> Appeal Communication to TC (Appeal Notice, Brief, Reply Brief) <input type="checkbox"/> Proprietary Information <input type="checkbox"/> Status Letter <input checked="" type="checkbox"/> Other Enclosure(s) (please identify below): ** Form PTO-1449 (five pages)
Remarks		

SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT		
Firm Name	Alleman Hall McCoy Russell & Tuttle LLP	
Signature	<i>Michael Matthews Hall</i>	
Printed name	Michael Matthews Hall	
Date	January 19, 2005	Reg. No. 43,653

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Date: January 19, 2005

CHUNG J. LEE, OANH NGUYEN,  
WEI SHIANG CHARLES LEE,  
MICHAEL SOLOMENSKY, ATUL KUMAR,  
JAMES YU CHUNG CHANG, and BINH NGUYEN

Serial No. : 10/820,447

Group Art Unit 3746

Filed : April 7, 2004

For : PROCESS MODULES FOR TRANSPORT  
POLYMERIZATION OF LOW EPSILON THIN FILMS

Mail Stop AMENDMENT  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

Sir:

**INFORMATION DISCLOSURE STATEMENT**  
**UNDER 37 C.F.R. §§ 1.56, 1.97, and 1.98**

Applicants are submitting this Information Disclosure Statement pursuant to 37 C.F.R. §§ 1.56, 1.97, and 1.98 to disclose to the U.S. Patent and Trademark Office the patents, publications, applications, and/or other references listed on the enclosed, completed PTO-1449 form(s). The filing of this Information Disclosure Statement should not be construed as a representation that a search has been made or as an admission that the listed references are prior art for this application. Applicants respectfully request that the listed references be expressly considered during prosecution of the application, and that the references be made of record therein and appear among the "references cited" on any patents issuing therefrom.

Page 1 — INFORMATION DISCLOSURE STATEMENT ...  
Serial No. 10/820,447

### CONTENT OF DISCLOSURE

This Information Disclosure Statement includes five pages of PTO-1449 forms. However, because this application claims priority to an earlier filed application (Serial No. 10/126,919, filed April 19, 2002), copies of references are not included, in accordance with 37 CFR § 1.98(d)(1).


### TIMING OF DISCLOSURE / FEE INFORMATION

This Information Disclosure Statement is being filed, to the best of the undersigned's knowledge, either (1) before the mailing of a first Office action on the merits, or (2) before the mailing of a first Office action after the filing of a request for continued examination under 37 C.F.R. § 1.114. Therefore, in accordance with 37 C.F.R. § 1.97(b), no fee or statement under 37 C.F.R. § 1.97(e) is required.

Please contact the undersigned with any questions or comments regarding this Information Disclosure Statement.

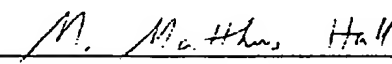
#### CERTIFICATE OF FACSIMILE

I hereby certify that this correspondence is being facsimile transmitted to the U.S. Patent Office, facsimile number: (703) 872-9306 on January 19, 2005.

  
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Respectfully submitted,

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Attorney for Assignee

SHEET 1 OF 5

FORM PTO-1449		DOCKET NUMBER DSI 313CON		APPLICATION NUMBER 10/820,447		
INFORMATION DISCLOSURE CITATION IN AN APPLICATION		APPLICANTS Chung J. Lee et al.				
		FILING DATE April 7, 2004		GROUP ART UNIT 3746		
U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FIL. DATE IF APPROP.
	3,268,599	08/23/1966	Chow			
	3,274,267	09/20/1966	Chow			
	3,280,202	10/18/1966	Gilch			
	3,288,728	11/29/1966	Gorham			
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	3,379,803	04/23/1968	Tittmann et al.			
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FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO
	EP 0 349 032 A2	01/03/1990	EPO			X
	EP 0 523 479 A2	01/20/1993	EPO			X
	EP 0 856 503 A1	08/05/1998	EPO			X
OTHER DOCUMENTS						
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EXAMINER			DATE CONSIDERED			

SHEET 2 OF 5

FORM PTO-1449		DOCKET NUMBER DSI 313CON		APPLICATION NUMBER 10/820,447		
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	3,626,032	12/07/1971	Norris			
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	5,879,808	03/09/1999	Wary et al.			
	5,958,510	09/28/1999	Sivaramakrishnam			
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO
	GB 650 947	03/07/1951	Great Britain			X
	GB 673 651	06/11/1952	Great Britain			X
	WO 97/15699	05/01/1997	WIPO			X
OTHER DOCUMENTS						
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EXAMINER			DATE CONSIDERED			

SHEET 3 OF 5

FORM PTO-1449  INFORMATION DISCLOSURE CITATION IN AN APPLICATION		DOCKET NUMBER DSI 313CON		APPLICATION NUMBER 10/820,447		
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	2003/0143341	7/31/2003	Lee			
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO
	WO 97/15951	05/01/1997	WIPO			X
	WO 97/42356	11/13/1997	WIPO			X
	WO 99/21705	05/06/1999	WIPO			X
OTHER DOCUMENTS						
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FOREIGN PATENT DOCUMENTS								
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO		
	WO 99/21706	05/06/1999	WIPO			X		
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OTHER DOCUMENTS								
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SHEET 5 OF 5

FORM PTO-1449  INFORMATION DISCLOSURE CITATION IN AN APPLICATION		DOCKET NUMBER DSI 313CON		APPLICATION NUMBER 10/820,447		
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FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO
OTHER DOCUMENTS						
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EXAMINER			DATE CONSIDERED			